

EVVOSEMI[®]

THINK CHANGE DO



ESD



TVS



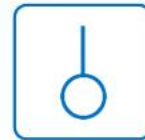
MOS



LDO



Diode



Sensor



DC-DC

Product Specification

▶ Domestic	Part Number	EV2SC5200-T71
▶ Overseas	Part Number	2SC5200
▶ Equivalent	Part Number	2SC5200

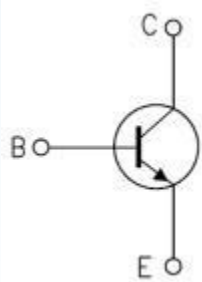
"T71" means TO-3PL

EV is the abbreviation of name EVVO

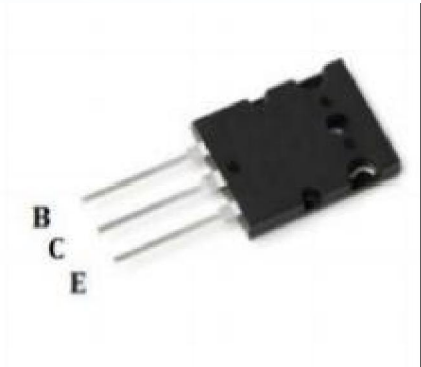
Silicon NPN transistor

Features:

- ① Power Amplifier Applications
- ② Complementary to 2SA1943
- ③ High collector voltage:VCEO=230V (min)
- ④ Recommended for 100-W high-fidelity audio frequency amplifier Output stage



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



MINOS TO-3PL

Absolute Maximum Ratings (Tc=25℃)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V _{CBO}	230	V
Collector-emitter voltage		V _{CEO}	230	V
Emitter-base voltage		V _{EBO}	7	V
Collector current		I _C	17	A
Base current		I _B	3	A
Collector power dissipation	T _c =25℃	P _C	180	W
Junction temperature		T _j	150	℃
Storage temperature range		T _{STG}	-55~150	℃

Package Marking And Ordering Information:

Ordering Codes	Package	Product Code	Packing
2SC5200	TO-3PL	5200	Tube

Silicon NPN transistor

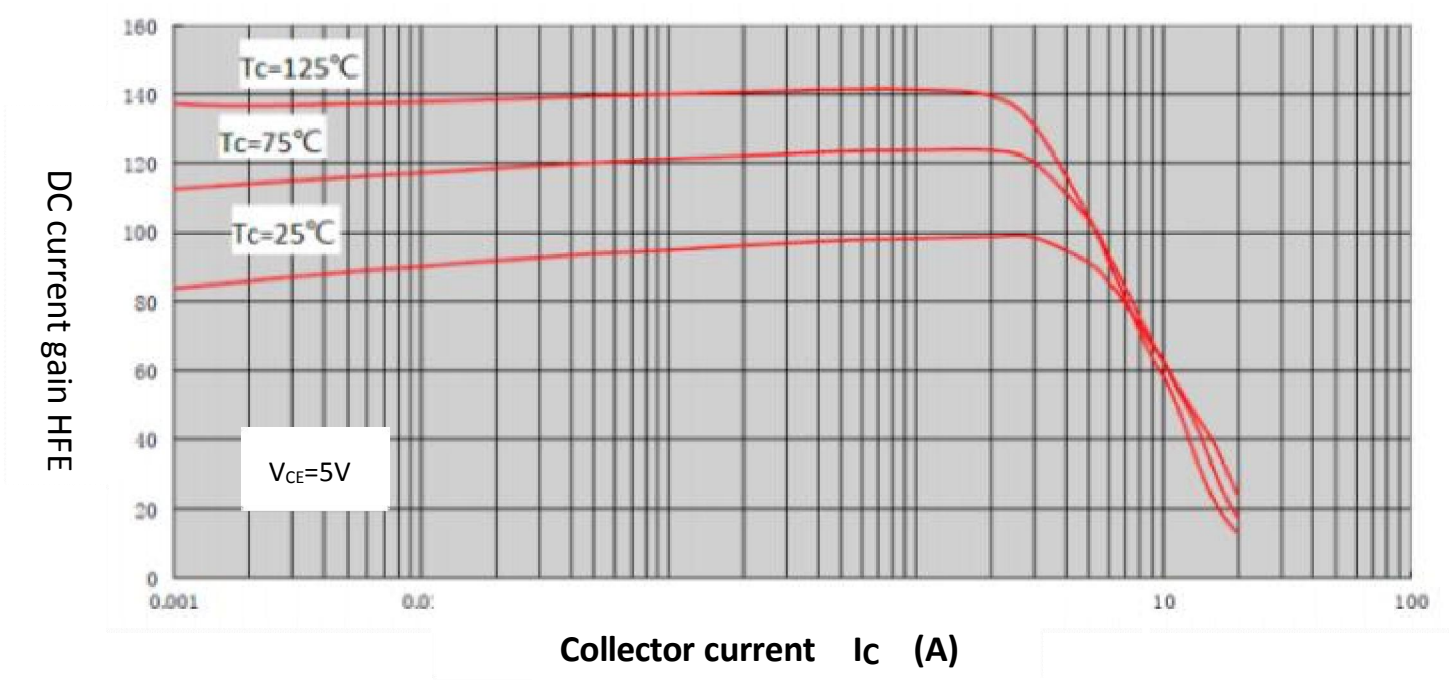
Electrical CharacteristicsTc= (25℃)

Characteristics	Symbol	Test Condition	Min	Typ	Max	Unit
Collector cut-off current	ICBO	VCB=230V; IE=0			500	uA
Emitter cut-off current	IEBO	VEB=7V; IC=0			500	uA
Dc current gain	hFE	IC=5A; VCE=4V;	70		140	
Collector-emitter saturation voltage	VCE(sat)	IC=4A; IB=0.4A			0.5	V
Transition frequency	fT	VCE=10V; IC=500mA ;f=1MHZ		58		MHZ

Symbol	Paramter	Typ	Units
RθJC	Junction-to-Case	0.68	℃/W

TYPICAL CHARACTERISTICS

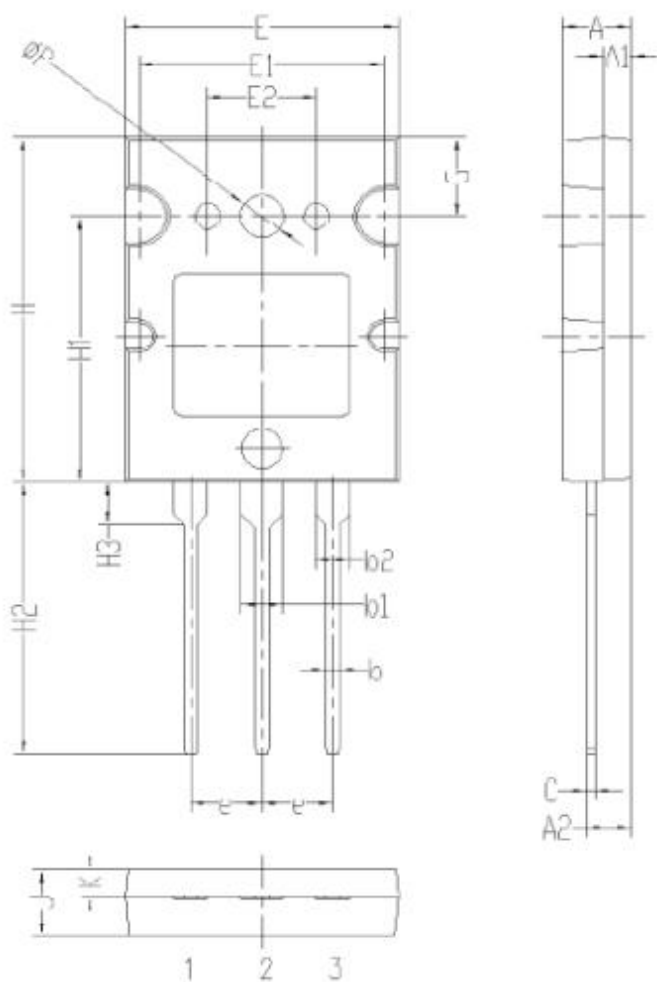
HFE--IC



Silicon NPN transistor

Package Information

TO-3PL PACKAGE



	單位 mm		
	MIN	NOM	MAX
A	4.8	5	5.2
A'	1.8	2	2.2
A2	3	3.2	3.4
b	0.8	1	1.2
b1	2.8	3	3.2
b2	2.3	2.5	2.7
c	0.4	0.6	0.8
e	5.25	5.45	5.65
E	19.8	20	20.2
E1	17.8	18	18.2
E2	7.8	8	8.2
H	25.8	26	26.2
H1	19.8	20	20.2
H2	20	20.5	21
H3	3.05	3.25	3.45
G	5.8	6	6.2
ØP	3.1	3.3	3.5
J	4.8	5	5.2
K	1.8	2	2.2

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